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F. Esaka, K. Furuya, H. Shimada, M. Imamura, N. Matsubayashi, et al.. XAS Study on the Intermediate Species Formed During the Surface Oxidation of CrN Films. Journal de Physique IV Proceedings, 1997, 7 (C2), pp.C2-1149-C2-1150. 10.1051/jp4:19972167 . jpa-00255231

HAL Id: jpa-00255231 https://hal.science/jpa-00255231

Submitted on 4 Feb 2008

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XAS Study on the Intermediate Species Formed During the Surface Oxidation of CrN Films

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Abstract. XAS was applied to the identification of the intermediate species formed during the surface oxidation of CrN films. The NK-edge XAS spectra indicated formation of an intermediate species which gave a feature at 401.4 eV. A high resolution XAS spectrum exhibited that the feature at 401.4 eV has the same vibration splitting as that of gaseous N₂. It was also found that the species assigned to molecular N₂ occurred in the interstitial position of the surface oxide layer in the oxidized films. The result implied the importance of high energy resolution XAS in the field of material science.

1. INTRODUCTION

CrN is used for surface coatings to improve the hardness and corrosion resistance of various mechanical tools. During the use under an oxidizing atmosphere at a high temperature, these film properties fail due to the formation of surface oxide layer. There have been several studies on the surface oxidation mechanisms of CrN films [1], however, no detailed discussion was carried out on the intermediate species during surface oxidation. In previous reports [2,3], we investigated the surface oxidation of CrN films by x-ray absorption spectroscopy (XAS) and suggested that molecular N_2 is formed in the interstitial position of the surface oxide layer. The purpose of the present study is to obtain the evidence which shows that the intermediate species is molecular N_2 . In addition, in-depth distribution of the nitrogen species is investigated by changing the analysis depth of XAS.

2. EXPERIMENTAL PROCEDURE

CrN films with a thickness of 3 μ m were deposited on austenite stainless steel by a cathodic arc ion-plating method. The deposition procedures were described in detail in a previous report [4]. Surface oxidation of the CrN film was performed at 400 °C for 1 h in a flow of dry air (50 cm³ / min.). All XAS measurements were performed at the BL-13C of the Photon Factory [5]. The angle between the incident x-ray and the sample surface was set at 90°. XAS spectra were recorded with total electron yield (TEY), partial electron yield (PEY) with a retarding voltage of 270 V and x-ray fluorescence yield (FY) modes. All the spectra were normalized by dividing the signals by the signals recorded by a gold mesh located at the upstream side of the sample.

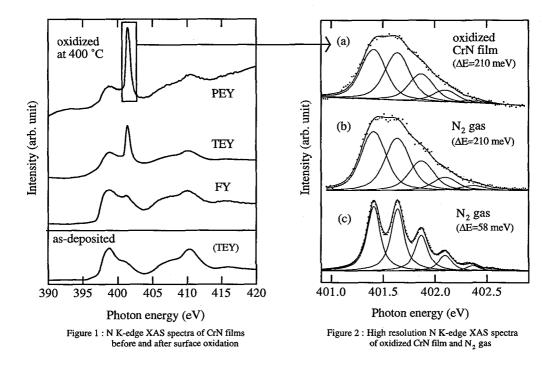
3. RESULTS AND DISCUSSION

Fig. 1 shows the N K-edge XAS spectra of the CrN films before and after surface oxidation. The TEY spectrum of the film before surface oxidation exhibits only the features assigned to CrN. In the PEY and TEY spectra of the oxidized film, a sharp feature attributed to an intermediate species is observed at 401.4 eV with a full width at half maximum (FWHM) value of 0.7 eV besides the CrN features. This feature is scarcely observed in the FY spectrum. Probing depths for each detection mode is <20 Å in PEY, 20-100 Å in TEY and > 1000 Å in FY. This indicates that the intermediate species is present predominantly in the surface oxide layer of the oxidized film.

In previous reports [2,3], we assigned the feature at 401.4 eV to molecular N_2 by comparing the photon energies of the features. To confirm the assignment, N K-edge XAS spectra of gaseous N_2 have been measured and compared with that of the oxidized film as shown in Fig. 2. The obtained spectra are fitted by a least-square method using mixed Gaussian-Lorentzian envelopes with a fixed Lorentzian width of 128 meV. The obtained Gaussian width corresponds to the line-width of the incident x-ray, indicated as C2-1150

 ΔE in Fig. 2. When the entrance and exit slit widths are quite narrow, well split vibration structures are observed as shown in Fig. 2(c). However, the signal intensity from the oxidized film is not high enough to measure the spectrum under the same instrumental conditions. Thus, the spectrum is compared with the spectrum of molecular N₂ measured at a moderate energy resolution of ΔE = 210 meV. The comparison evidently indicates that the intermediate species in the oxidized film is molecular N₂. The vibration splitting precludes the formation of atomic nitrogen which was suggested by Soriano et al. [6].

In conclusion, the present high resolution XAS result has confirmed the assignment that the intermediate species in the oxidized CrN film is molecular N_2 . This indicates the importance of the high resolution XAS for material science. In addition, it is found that XAS can be used for acquiring in-depth information by using various detection modes.



Acknowledgements

This work has been performed with the approval of the Photon Factory Programme Advisory Committee (PF-PAC No. 96-G144). F. E. was grateful for the Research Fellowships of the Japan Society for the Promotion of Science for Young Scientists.

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